

TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

SM3GZ47,SM3JZ47

AC POWER CONTROL APPLICATIONS

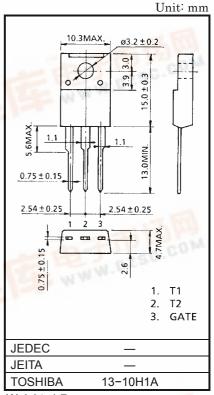
Repetitive Peak Off-State Voltage : V_{DRM} = 400, 600V
 R.M.S ON-State Current : I_T (RMS) = 3A

• High Commutating (dv / dt)

• Isolation Voltage :VISOL = 1500V AC

MAXIMUM RATINGS

CHARACTERIS	SYMBOL	RATING	UNIT		
Repetitive Peak	SM3GZ47	V _{DRM}	400	V	
Off-State Voltage	SM3JZ47	V DRM	600		
R.M.S On-State Current (Full Sine Waveform Tc =	I _{T (RMS)}	3	А		
Peak One Cycle Surge On-State Current (Non-Repetitive)		l-o	30 (50Hz)	Α	
		ITSM	33 (60Hz)		
I ² t Limit Value (t = 1~10ms)		l ² t	4.5	A ² s	
Critical Rate of Rise of O Current	di / dt	50	A / µs		
Peak Gate Power Dissipa	P _{GM}	5	W		
Average Gate Power Dissipation		P _G (AV)	0.5	W	
Peak Gate Voltage		V_{GM}	10	٧	
Peak Gate Current	I _{GM}	2	Α		
Junction Temperature	Tj	-40~125	°C		
Storage Temperature Ra	T _{stg}	-40~125	°C		
Isolation Voltage (AC, t =	V _{ISOL}	1500	V		



Weight: 1.7g

Note 1: di / dt test condition $V_{DRM} = 0.5 \times Rated$ $I_{TM} \le 4.5A$ $t_{gw} \ge 10 \mu s$ $t_{gr} \le 250 n s$ $i_{gp} = I_{GT} \times 2.0$

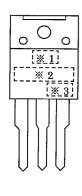


TOSHIBA

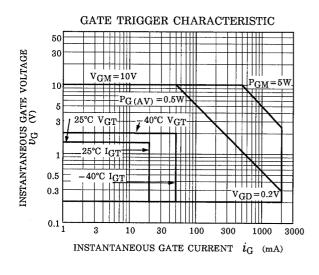
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

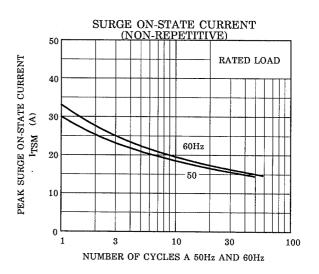
CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current		I _{DRM}	V _{DRM} = Rated		_	_	20	μА
Gate Trigger Voltage	I	V _{GT}	V _D = 12V R _L = 20Ω	T2 (+), Gate (+)	_	_	1.5	V
	II			T2 (+), Gate (-)	_	_	1.5	
	III			T2 (-), Gate (-)	_	_	1.5	
	IV			T2 (-), Gate (+)	_	_	_	
Gate Trigger Current	I	Ідт	V _D = 12V R _L = 20Ω	T2 (+), Gate (+)	_	_	20	- mA
	II			T2 (+), Gate (-)	_	_	20	
	III			T2 (-), Gate (-)	_	_	20	
	IV			T2 (-), Gate (+)	_	_	_	
Peak On-State Voltage V _{TM} I _{TM} = 4.5A		_	_	1.5	V			
Gate Non-Trigger Voltage		V_{GD}	V _D = Rated, Tc = 125°C		0.2	_	_	V
Holding Current		I _H	V _D = 12V, I _{TM} = 1A		_	_	30	mA
Thermal Resistance		R _{th (j−c)}	Junction to Case, AC		_	_	4.2	°C/W
Critical Rate of Rise of Off-State Voltage		dv / dt	V _{DRM} = Rated, T _j = 125°C Exponential Rise		_	300	_	V / µs
Critical Rate of Rise of Off-State Voltage at Commutation		(dv / dt) c	$V_{DRM} = 400V, T_j = 125$ °C (di /dt) c = -2.0A / ms		10	_	_	V / µs

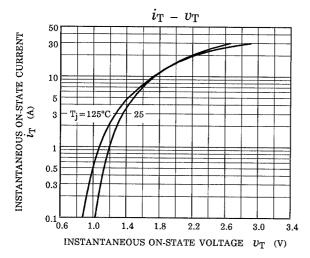
MARKING

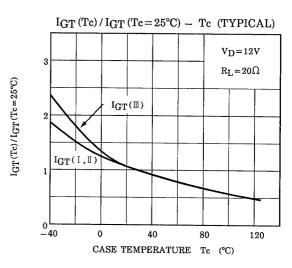


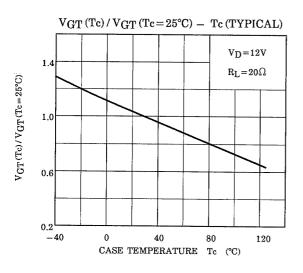
NUMBER		MARK		
* 1	TOSHIBA PRODUC	7		
* 2	TYPE	SM3GZ47	M3GZ47	
		SM3JZ47	M3JZ47	
* 3	Lot Number Month (Starting from Alphabet A) Year (Last Decimal Digit of the Current Year)		Example 8A : January 1998 8B : Febrary 1998 8L : December 1998	

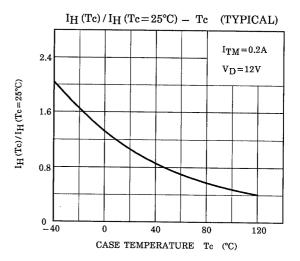




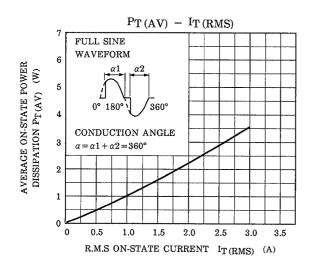


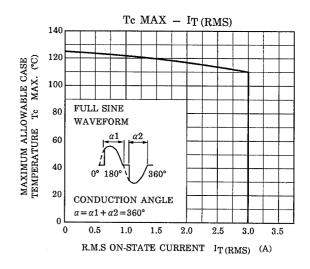


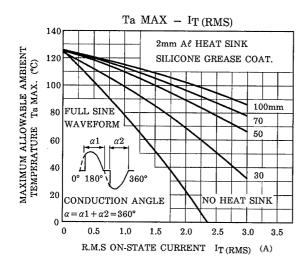


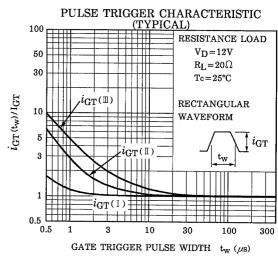


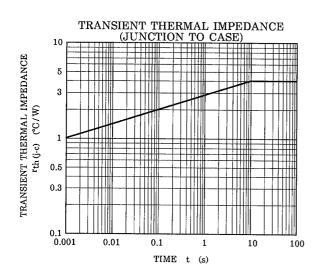
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